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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	50MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	3.3V
Operating Temperature	-40°C ~ 95°C (TA)
Security Features	-
Package / Case	256-BBGA
Supplier Device Package	256-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/xpc850cvr50bur2

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NP,

2 Features

Figure 1 is a block diagram of the MPC850, showing its major components and the relationships among those components:

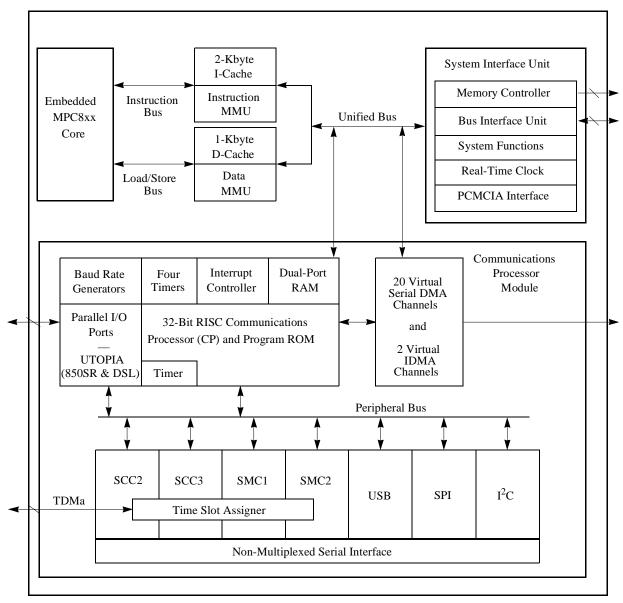


Figure 1. MPC850 Microprocessor Block Diagram

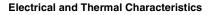
The following list summarizes the main features of the MPC850:

- Embedded single-issue, 32-bit MPC8xx core (implementing the PowerPC architecture) with thirty-two 32-bit general-purpose registers (GPRs)
 - Performs branch folding and branch prediction with conditional prefetch, but without conditional execution



Features

- 2-Kbyte instruction cache and 1-Kbyte data cache (Harvard architecture)
 - Caches are two-way, set-associative
 - Physically addressed
 - Cache blocks can be updated with a 4-word line burst
 - Least-recently used (LRU) replacement algorithm
 - Lockable one-line granularity
- Memory management units (MMUs) with 8-entry translation lookaside buffers (TLBs) and fully-associative instruction and data TLBs
- MMUs support multiple page sizes of 4 Kbytes, 16 Kbytes, 256 Kbytes, 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and eight protection groups
- Advanced on-chip emulation debug mode
- Data bus dynamic bus sizing for 8, 16, and 32-bit buses
 - Supports traditional 68000 big-endian, traditional x86 little-endian and modified little-endian memory systems
 - Twenty-six external address lines
- Completely static design (0–80 MHz operation)
- System integration unit (SIU)
 - Hardware bus monitor
 - Spurious interrupt monitor
 - Software watchdog
 - Periodic interrupt timer
 - Low-power stop mode
 - Clock synthesizer
 - Decrementer, time base, and real-time clock (RTC) from the PowerPC architecture
 - Reset controller
 - IEEE 1149.1 test access port (JTAG)
- Memory controller (eight banks)
 - Glueless interface to DRAM single in-line memory modules (SIMMs), synchronous DRAM (SDRAM), static random-access memory (SRAM), electrically programmable read-only memory (EPROM), flash EPROM, etc.
 - Memory controller programmable to support most size and speed memory interfaces
 - Boot chip-select available at reset (options for 8, 16, or 32-bit memory)
 - Variable block sizes, 32 Kbytes to 256 Mbytes
 - Selectable write protection
 - On-chip bus arbiter supports one external bus master
 - Special features for burst mode support
- General-purpose timers
 - Four 16-bit timers or two 32-bit timers





- Separate power supply input to operate internal logic at 2.2 V when operating at or below 25 MHz
- Can be dynamically shifted between high frequency (3.3 V internal) and low frequency (2.2 V internal) operation
- Debug interface

(GND = 0V)

- Eight comparators: four operate on instruction address, two operate on data address, and two
 operate on data
- The MPC850 can compare using the =, \neq , <, and > conditions to generate watchpoints
- Each watchpoint can generate a breakpoint internally
- 3.3-V operation with 5-V TTL compatibility on all general purpose I/O pins.

3 Electrical and Thermal Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC850. Table 2 provides the maximum ratings.

Rating	Symbol	Value	Unit
Supply voltage	VDDH	-0.3 to 4.0	V
	VDDL	-0.3 to 4.0	V
	KAPWR	-0.3 to 4.0	V
	VDDSYN	-0.3 to 4.0	V
Input voltage ¹	V _{in}	GND-0.3 to VDDH + 2.5 V	V
Junction temperature ²	Тј	0 to 95 (standard) -40 to 95 (extended)	°C
Storage temperature range	T _{stg}	-55 to +150	°C

Table 2. Maximum Ra

¹ Functional operating conditions are provided with the DC electrical specifications in Table 5. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device. CAUTION: All inputs that tolerate 5 V cannot be more than 2.5 V greater than the supply voltage. This restriction

applies to power-up and normal operation (that is, if the MPC850 is unpowered, voltage greater than 2.5 V must not be applied to its inputs).

² The MPC850, a high-frequency device in a BGA package, does not provide a guaranteed maximum ambient temperature. Only maximum junction temperature is guaranteed. It is the responsibility of the user to consider power dissipation and thermal management. Junction temperature ratings are the same regardless of frequency rating of the device.

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{CC}). Table 3 provides the package thermal characteristics for the MPC850.



		50 MHz 66 MHz		80 MHz			Cap Load	11		
Num	Characteristic	Min	Max	Min	Max	Min	Мах	FFACT	(default 50 pF)	Unit
B9	CLKOUT to A[6–31] RD/WR, BURST, D[0–31], DP[0–3], TSIZ[0–1], REG, RSV, AT[0–3], PTR high-Z	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B11	CLKOUT to \overline{TS} , \overline{BB} assertion	5.00	11.00	7.58	13.58	6.25	12.25	0.250	50.00	ns
B11a	CLKOUT to \overline{TA} , \overline{BI} assertion, (When driven by the memory controller or PCMCIA interface)	2.50	9.25	2.50	9.25	2.50	9.25	—	50.00	ns
B12	CLKOUT to \overline{TS} , \overline{BB} negation	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B12a	CLKOUT to TA, BI negation (when driven by the memory controller or PCMCIA interface)	2.50	11.00	2.50	11.00	2.50	11.00	—	50.00	ns
B13	CLKOUT to \overline{TS} , \overline{BB} high-Z	5.00	19.00	7.58	21.58	6.25	20.25	0.250	50.00	ns
B13a	CLKOUT to \overline{TA} , \overline{BI} high-Z, (when driven by the memory controller or PCMCIA interface)	2.50	15.00	2.50	15.00	2.50	15.00	—	50.00	ns
B14	CLKOUT to \overline{TEA} assertion	2.50	10.00	2.50	10.00	2.50	10.00	—	50.00	ns
B15	CLKOUT to TEA high-Z	2.50	15.00	2.50	15.00	2.50	15.00	—	50.00	ns
B16	$\overline{\text{TA}}$, $\overline{\text{BI}}$ valid to CLKOUT(setup time) ⁵	9.75	—	9.75	—	9.75	—	—	50.00	ns
B16a	TEA, KR, RETRY, valid to CLKOUT (setup time) ⁵	10.00	—	10.00	—	10.00	—	—	50.00	ns
B16b	$\overline{\text{BB}}$, $\overline{\text{BG}}$, $\overline{\text{BR}}$ valid to CLKOUT (setup time) ⁶	8.50	_	8.50	—	8.50	—	_	50.00	ns
B17	$\frac{\text{CLKOUT to TA, TEA, BI, BB,}}{\text{BG, BR valid (Hold time).}^5}$	1.00		1.00	—	1.00	_	_	50.00	ns
B17a	CLKOUT to KR, RETRY, except TEA valid (hold time)	2.00	—	2.00	—	2.00	—	_	50.00	ns
B18	D[0–31], DP[0–3] valid to CLKOUT rising edge (setup time) ⁷	6.00	_	6.00		6.00		_	50.00	ns
B19	CLKOUT rising edge to D[0–31], DP[0–3] valid (hold time) ⁷	1.00	_	1.00		1.00		_	50.00	ns
B20	D[0–31], DP[0–3] valid to CLKOUT falling edge (setup time) ⁸	4.00		4.00		4.00	—	_	50.00	ns
B21	CLKOUT falling edge to D[0–31], DP[0–3] valid (hold time) ⁸	2.00	—	2.00		2.00	—	—	—	

Table 6.	Bus Operation Timing	¹ (continued)
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[
Num	Characteristic	50 MHz 66 MHz		80 MHz		FFACT	Cap Load (default	Unit		
-		Min	Max	Min	Max	Min	Max	_	50 pF)	
B28c	CLKOUT falling edge to WE[0–3] negated GPCM write access TRLX = 0,1 CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B28d	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	_	14.00	_	18.00	_	16.00	0.375	50.00	ns
B29	$\overline{WE[0-3]}$ negated to D[0-31], DP[0-3] high-Z GPCM write access, CSNT = 0	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B29a	WE[0–3] negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0 CSNT = 1, EBDF = 0	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B29b	CS negated to D[0–31], DP[0–3], high-Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0	3.00		6.00		4.00		0.250	50.00	ns
B29c	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	8.00		13.00		11.00		0.500	50.00	ns
B29d	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	28.00		43.00		36.00		1.500	50.00	ns
B29e	CS negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	28.00		43.00		36.00		1.500	50.00	ns
B29f	WE[0–3] negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	5.00		9.00		7.00		0.375	50.00	ns
B29g	CS negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	5.00		9.00		7.00		0.375	50.00	ns

Table 6.	Bus Operation	Timing ¹	(continued)
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Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default	Unit
Num	Unaracteristic	Min	Max	Min	Max	Min	Max	11401	50 pF)	Unit
B42	CLKOUT rising edge to \overline{TS} valid (hold time)	2.00	_	2.00	_	2.00	_	_	50.00	ns
B43	AS negation to memory controller signals negation	_	TBD	_	TBD	TBD	_	—	50.00	ns

 Table 6. Bus Operation Timing ¹ (continued)

The minima provided assume a 0 pF load, whereas maxima assume a 50pF load. For frequencies not marked on the part, new bus timing must be calculated for all frequency-dependent AC parameters. Frequency-dependent AC parameters are those with an entry in the FFactor column. AC parameters without an FFactor entry do not need to be calculated and can be taken directly from the frequency column corresponding to the frequency marked on the part. The following equations should be used in these calculations.

For a frequency F, the following equations should be applied to each one of the above parameters: For minima:

$$D = \frac{FFACTOR \times 1000}{F} + (D_{50} - 20 \times FFACTOR)$$

For maxima:

$$D = \frac{FFACTOR \times 1000}{F} + \frac{(D_{50} - 20 \times FFACTOR)}{F} + \frac{1 ns(CAP \ LOAD - 50) / 10}{F}$$

where:

D is the parameter value to the frequency required in ns

F is the operation frequency in MHz

D₅₀ is the parameter value defined for 50 MHz

CAP LOAD is the capacitance load on the signal in question.

FFACTOR is the one defined for each of the parameters in the table.

- ² Phase and frequency jitter performance results are valid only if the input jitter is less than the prescribed value.
- ³ If the rate of change of the frequency of EXTAL is slow (i.e. it does not jump between the minimum and maximum values in one cycle) or the frequency of the jitter is fast (i.e., it does not stay at an extreme value for a long time) then the maximum allowed jitter on EXTAL can be up to 2%.
- ⁴ The timing for BR output is relevant when the MPC850 is selected to work with external bus arbiter. The timing for BG output is relevant when the MPC850 is selected to work with internal bus arbiter.
- ⁵ The setup times required for TA, TEA, and BI are relevant only when they are supplied by an external device (and not when the memory controller or the PCMCIA interface drives them).
- ⁶ The timing required for BR input is relevant when the MPC850 is selected to work with the internal bus arbiter. The timing for BG input is relevant when the MPC850 is selected to work with the external bus arbiter.
- ⁷ The D[0–31] and DP[0–3] input timings B20 and B21 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.
- ⁸ The D[0:31] and DP[0:3] input timings B20 and B21 refer to the falling edge of CLKOUT. This timing is valid only for read accesses controlled by chip-selects controlled by the UPM in the memory controller, for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.
- ⁹ The timing B30 refers to \overline{CS} when ACS = '00' and to $\overline{WE[0:3]}$ when CSNT = '0'.
- ¹⁰ The signal UPWAIT is considered asynchronous to CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals.
- ¹¹ The $\overline{\text{AS}}$ signal is considered asynchronous to CLKOUT.



Figure 4 provides the timing for the synchronous output signals.

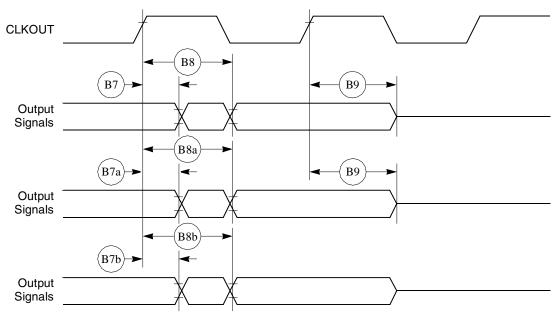


Figure 4. Synchronous Output Signals Timing

Figure 5 provides the timing for the synchronous active pull-up and open-drain output signals.

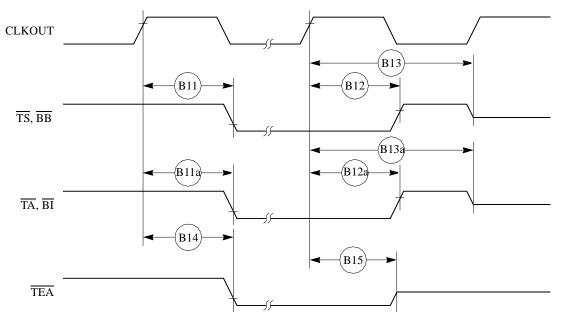


Figure 5. Synchronous Active Pullup and Open-Drain Outputs Signals Timing



Figure 8 provides the timing for the input data controlled by the UPM in the memory controller.

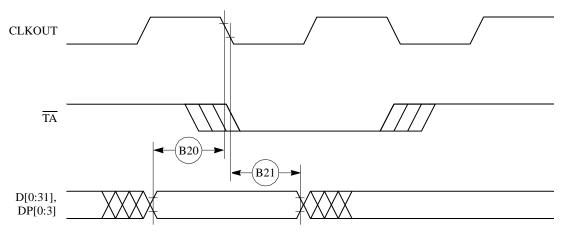


Figure 8. Input Data Timing when Controlled by UPM in the Memory Controller

Figure 9 through Figure 12 provide the timing for the external bus read controlled by various GPCM factors.

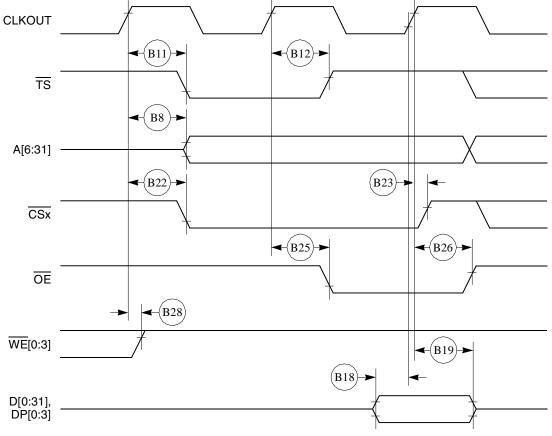


Figure 9. External Bus Read Timing (GPCM Controlled—ACS = 00)



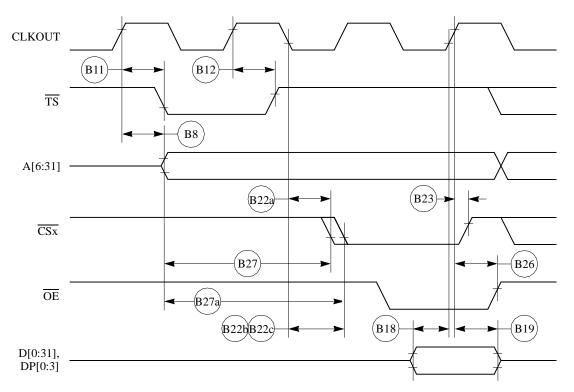


Figure 12. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)



Figure 16 provides the timing for the external bus controlled by the UPM.

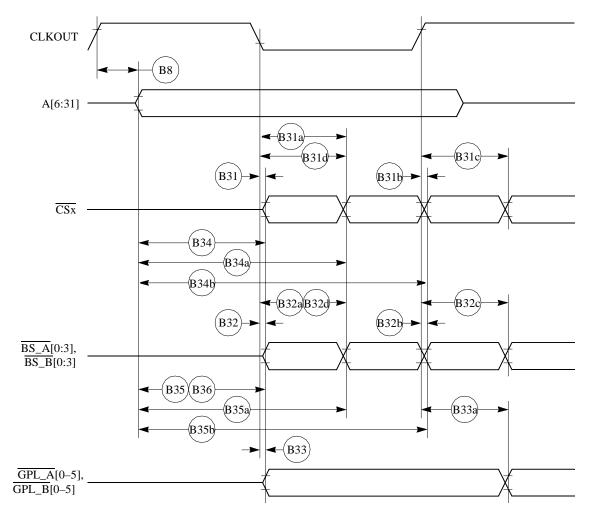


Figure 16. External Bus Timing (UPM Controlled Signals)



Figure 31 shows the reset timing for the data bus configuration.

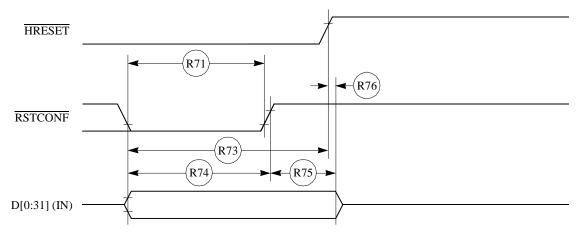


Figure 31. Reset Timing—Configuration from Data Bus

Figure 32 provides the reset timing for the data bus weak drive during configuration.

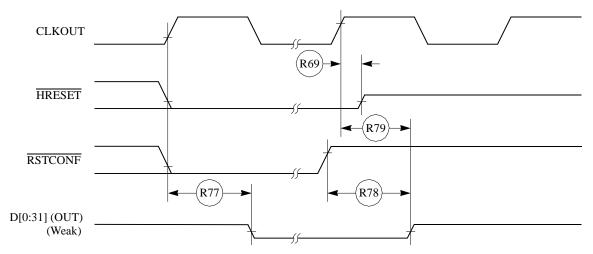


Figure 32. Reset Timing—Data Bus Weak Drive during Configuration



IEEE 1149.1 Electrical Specifications

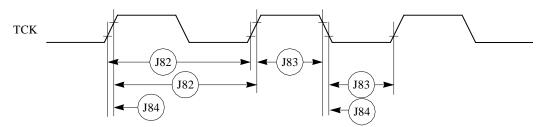


Figure 34. JTAG Test Clock Input Timing

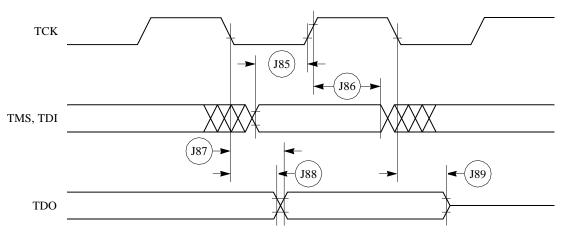


Figure 35. JTAG Test Access Port Timing Diagram

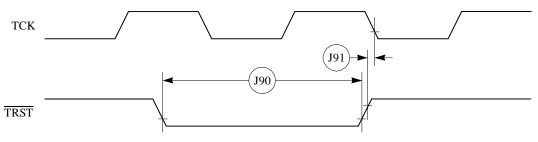


Figure 36. JTAG TRST Timing Diagram



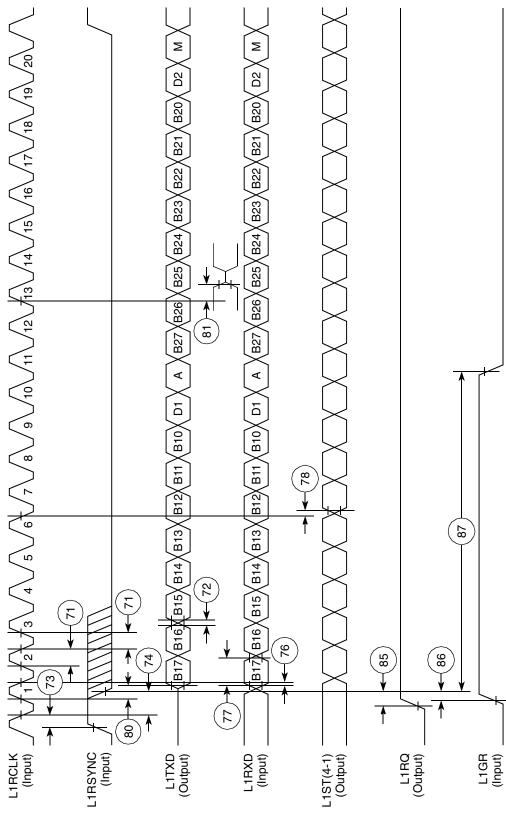
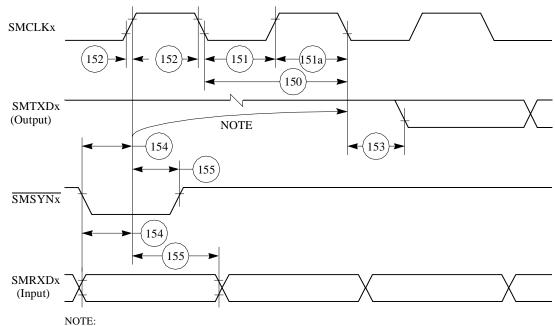


Figure 49. IDL Timing







1. This delay is equal to an integer number of character-length clocks.

Figure 56. SMC Transparent Timing Diagram

8.9 SPI Master AC Electrical Specifications

Table 22 provides the SPI master timings as shown in Figure 57 and Figure 58.

Num	Characteristic	All Frequ	Unit	
Num	Characteristic	Min	Max	Unit
160	MASTER cycle time	4	1024	t _{cyc}
161	MASTER clock (SCK) high or low time	2	512	t _{cyc}
162	MASTER data setup time (inputs)	50.00	_	ns
163	Master data hold time (inputs)	0.00	_	ns
164	Master data valid (after SCK edge)	—	20.00	ns
165	Master data hold time (outputs)	0.00	_	ns
166	Rise time output	—	15.00	ns
167	Fall time output	—	15.00	ns

Table 22. SPI Master Timing



CPM Electrical Characteristics

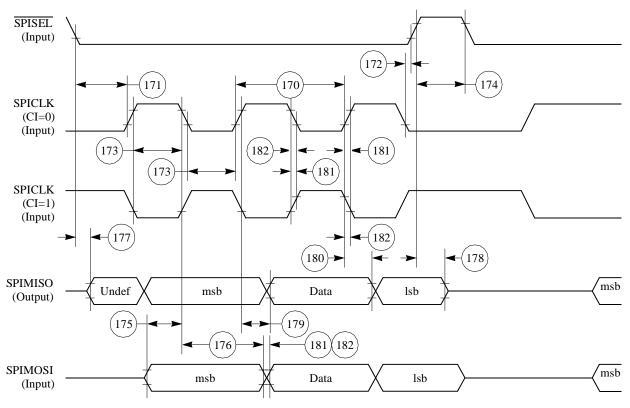


Figure 60. SPI Slave (CP = 1) Timing Diagram

8.11 I²C AC Electrical Specifications

Table 24 provides the I^2C (SCL < 100 KHz) timings.

Table 24.	I ² C Timing	(SCL < 100 KHz)
-----------	-------------------------	-----------------

Num	Characteristic	All Frequ	Unit	
Num			Мах	Unit
200	SCL clock frequency (slave)	0.00	100.00	KHz
200	SCL clock frequency (master) ¹	1.50	100.00	KHz
202	Bus free time between transmissions	4.70	_	μs
203	Low period of SCL	4.70	_	μs
204	High period of SCL	4.00		μs
205	Start condition setup time	4.70	_	μs
206	Start condition hold time	4.00		μs
207	Data hold time	0.00		μs
208	Data setup time	250.00		ns
209	SDL/SCL rise time	_	1.00	μs



CPM Electrical Characteristics

Num	Characteristic	All Frequ	Unit	
Num	onaracteristic	Min	Мах	onit
210	SDL/SCL fall time	_	300.00	ns
211	Stop condition setup time	4.70	_	μs

Table 24. I²C Timing (SCL < 100 KHz) (CONTINUED)

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(BRGCLK/pre_scaler) must be greater or equal to 4/1.

Table 25 provides the I^2C (SCL > 100 KHz) timings.

Table 25. I^2C Timing (SCL > 100 KHz)

Num	Characteristic	Expression	All Freq	Unit	
num			Min	Max	Unit
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions		1/(2.2 * fSCL)	—	s
203	Low period of SCL		1/(2.2 * fSCL)	—	s
204	High period of SCL		1/(2.2 * fSCL)	—	s
205	Start condition setup time		1/(2.2 * fSCL)	_	s
206	Start condition hold time		1/(2.2 * fSCL)	_	s
207	Data hold time		0	_	s
208	Data setup time		1/(40 * fSCL)	_	s
209	SDL/SCL rise time		—	1/(10 * fSCL)	s
210	SDL/SCL fall time		—	1/(33 * fSCL)	s
211	Stop condition setup time		1/2(2.2 * fSCL)	_	S

SCL frequency is given by SCL = BrgClk_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(Brg_Clk/pre_scaler) must be greater or equal to 4/1.

Figure 61 shows the I^2C bus timing.

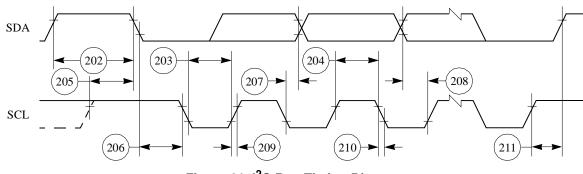


Figure 61. I²C Bus Timing Diagram



9 Mechanical Data and Ordering Information

Table 26 provides information on the MPC850 derivative devices.

Table 26.	MPC850	Family	/ Derivatives
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Device	Ethernet Support	Number of SCCs ¹	32-Channel HDLC Support	64-Channel HDLC Support ²
MPC850	N/A	One	N/A	N/A
MPC850DE	Yes	Two	N/A	N/A
MPC850SR	Yes	Two	N/A	Yes
MPC850DSL	Yes	Two	No	No

¹ Serial Communication Controller (SCC)

² 50 MHz version supports 64 time slots on a time division multiplexed line using one SCC

Table 27 identifies the packages and operating frequencies available for the MPC850.

 Table 27. MPC850 Package/Frequency/Availability

Package Type	Frequency (MHz)	Temperature (Tj)	Order Number
256-Lead Plastic Ball Grid Array (ZT suffix)	50	0°C to 95°C	XPC850ZT50BU XPC850DEZT50BU XPC850SRZT50BU XPC850DSLZT50BU
	66	0°C to 95°C	XPC850ZT66BU XPC850DEZT66BU XPC850SRZT66BU
	80	0°C to 95°C	XPC850ZT80BU XPC850DEZT80BU XPC850SRZT80BU
256-Lead Plastic Ball Grid Array (CZT suffix)	50	-40°C to 95°C	XPC850CZT50BU XPC850DECZT50BU XPC850SRCZT50BU XPC850DSLCZT50BU
	66		XPC850CZT66BU XPC850DECZT66BU XPC850SRCZT66BU
	80		XPC850CZT80B XPC850DECZT80B XPC850SRCZT80B

9.1 Pin Assignments and Mechanical Dimensions of the PBGA

The original pin numbering of the MPC850 conformed to a Freescale proprietary pin numbering scheme that has since been replaced by the JEDEC pin numbering standard for this package type. To support



Document Revision History

10 Document Revision History

Table 28 lists significant changes between revisions of this document.

Table 28. Document Revision History

Revision	Date	Change
2	7/2005	Added footnote 3 to Table 5 (previously Table 4.5) and deleted IOL limit.
1	10/2002	Added MPC850DSL. Corrected Figure 25 on page 34.
0.2	04/2002	Updated power numbers and added Rev. C
0.1	11/2001	Removed reference to 5 Volt tolerance capability on peripheral interface pins. Replaced SI and IDL timing diagrams with better images. Updated to new template, added this revision table.



Document Revision History

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